

TOSHIBA Transistor    Silicon NPN Triple Diffused Type (Darlington power transistor)

2SD1525

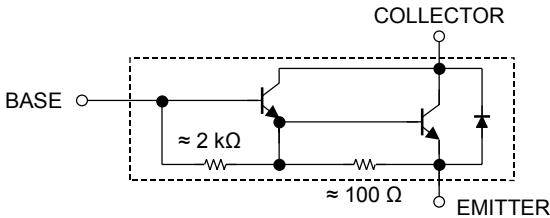
High Current Switching Applications

- High collector current:  $I_C = 30\text{ A}$
- High DC current gain:  $h_{FE} = 1000\text{ (min)}$  ( $V_{CE} = 5\text{ V}$ ,  $I_C = 20\text{ A}$ )
- Monolithic construction with built-in base-emitter shunt resistor.

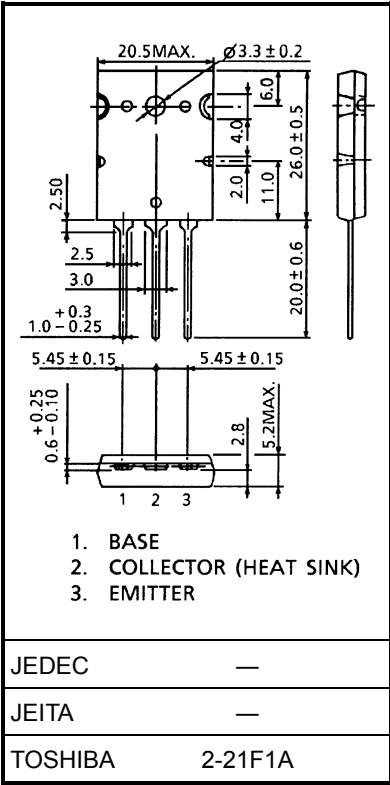
Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	100	V
Collector-emitter voltage	$V_{CEO}$	100	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	30	A
Base current	$I_B$	5	A
Collector power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_C$	150	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$

Equivalent Circuit

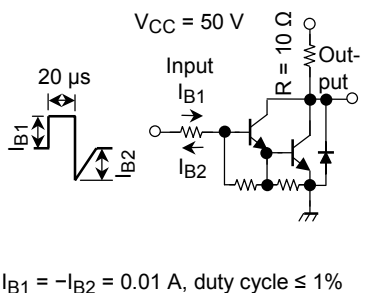


Unit: mm

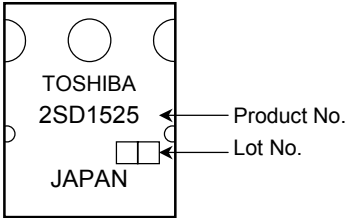


Weight: 9.75 g (typ.)

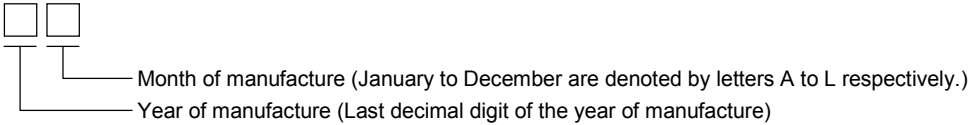
Electrical Characteristics (Ta = 25°C)

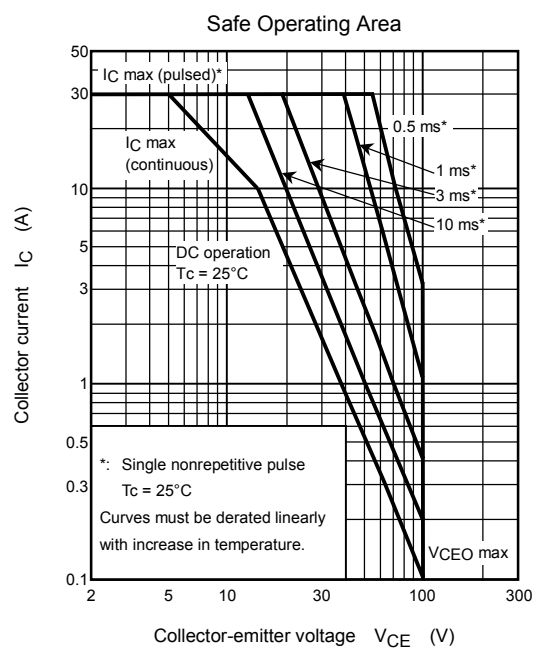
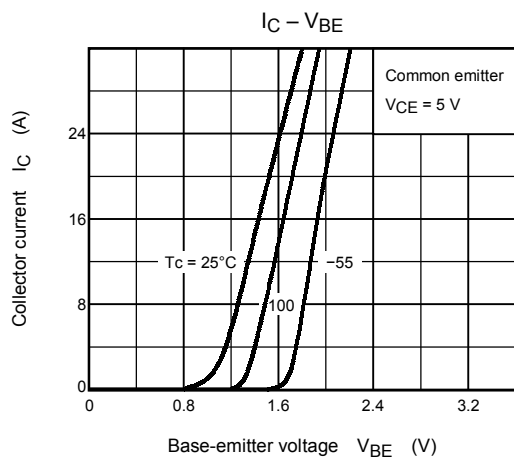
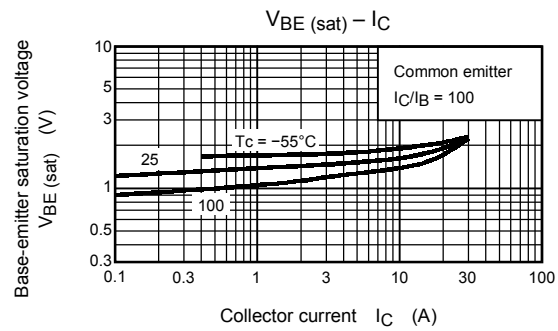
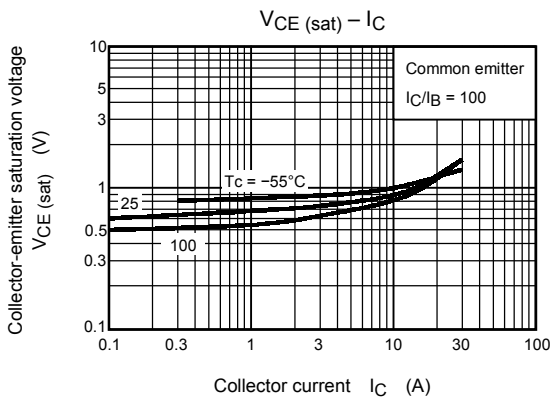
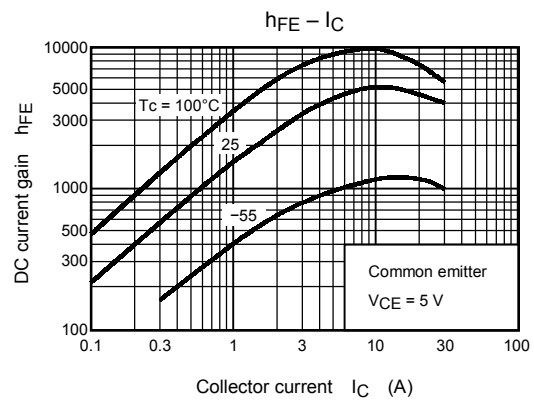
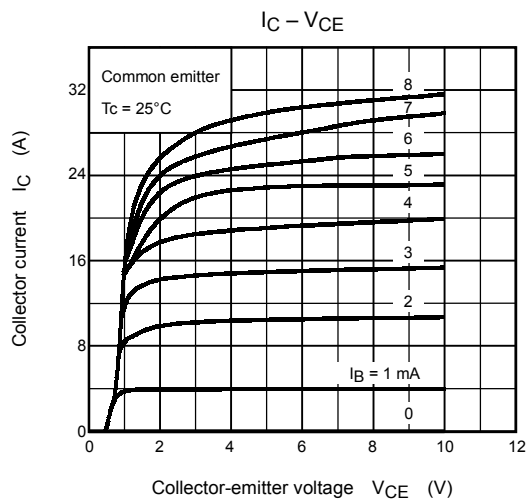
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		ICBO	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	—	—	100	μA
Emitter cut-off current		IEBO	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	—	—	10	mA
Collector-emitter breakdown voltage		V <sub>(BR)</sub> CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	100	—	—	V
DC current gain	h <sub>FE</sub> (1)		V <sub>CE</sub> = 5 V, I <sub>C</sub> = 20 A	1000	—	—	
	h <sub>FE</sub> (2)		V <sub>CE</sub> = 5 V, I <sub>C</sub> = 30 A	200	—	—	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 20 A, I <sub>B</sub> = 0.2 A	—	—	1.5	V
Base-emitter saturation voltage		V <sub>BE</sub> (sat)		—	—	2.5	V
Emitter-collector forward voltage		V <sub>ECF</sub>	I <sub>E</sub> = 10 A, I <sub>B</sub> = 0	—	—	3	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	—	10	—	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	—	500	—	pF
Switching time	Turn-on time	t <sub>on</sub>	 V <sub>CC</sub> = 50 V R = 10 Ω Input I <sub>B1</sub> I <sub>B2</sub> Output I <sub>B1</sub> = -I <sub>B2</sub> = 0.01 A, duty cycle ≤ 1%	—	1.5	—	μs
	Storage time	t <sub>stg</sub>		—	10	—	
	Fall time	t <sub>f</sub>		—	1.5	—	

Marking



Explanation of Lot No.





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